## **Slotted Optical Switch**

### OPB660N Obsolete (OPB660T)

### Features:

- Non-contact switching
- Printed circuit board mounting
- Enhanced signal to noise ratio
- Gap 0.125" (3.18 mm) wide and 0.345" (8.76 mm) deep slot
- Emitter Aperture 0.05" X 0.06" (1.27 mm X 1.52 mm)
- Sensor Aperture 0.01" X 0.06" (0.25 mm X 1.52 mm)

#### **Description:**

The OPB660N slotted optical switch consists of an infrared emitting diode and a NPN silicon phototransistor, combined with an enhanced low current roll-off that improves contrast ratio and provides immunity to background irradiance. Housings are made from an opaque grade of injection-molded plastic to minimize sensitivity to both visible and near-infrared light.

[12.32±0.25]

### **Applications:**

- Non-contact transmissive object sensor
- Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor
- Door sensor

Part Number	LED Peak Wavelength	Sensor	Slot Width / Depth	Aperture Emitter/Sensor	Lead Length / Spacing	
OPB660N		Rbe	0 425" ( 0 245"	0.05" (0.01"	0.100" / 0.320"	
OPB660T Obsolete	890 nm	Transistor	0.125" / 0.345"	0.05" / 0.01"	(MIN)	

[6.50±0.25]



Pin #	LED	Pin #	Transistor	
1	Anode	3	Collector	
2	Cathode	4	Emitter	





General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

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### **Electrical Specifications**

#### Absolute Maximum Ratings (T<sub>A</sub> = 25° C unless otherwise noted)

Storage & Operating Temperature Range	-40° C to +100° C
Lead Soldering Temperature [1/16 inch (1.6 mm) from the case for 5 sec. with soldering iron] $^{(1)}$	260° C
Input Diode	
Forward DC Current	50 mA
Peak Forward Current (1 μs pulse width, 300 pps)	1 A
Reverse DC Voltage	3 V
Power Dissipation <sup>(2)</sup>	100 mW
Output Phototransistor	-
Collector-Emitter Voltage	24 V
Collector DC Current	30 mA
Power Dissipation <sup>(3)</sup>	200 mW

### Electrical Characteristics (T<sub>A</sub> = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS	TEST CONDITIONS		
Input Diode								
$V_{\text{F}}$	Forward Voltage	-	-	1.6	V	I <sub>F</sub> = 10 mA		
I <sub>R</sub>	Reverse Current	-	-	100	μΑ	V <sub>R</sub> = 3 V		
Output Phototransistor								
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	24	-	-	V	I <sub>CE</sub> = 100 μA		
$BV_{ECO}$	Emitter Reverse Breakdown Voltage	0.4	-	-	V	I <sub>EC</sub> = 100 μA		
I <sub>CEO</sub>	Collector-Emitter Dark Current	-	-	100	μA	V <sub>CE</sub> = 5 V		

V <sub>SAT</sub>	Collector-Emitter Saturation Voltage	-	-	0.4	V	$I_{F}$ = 10 mA, $I_{C}$ = 100 $\mu A$ , (gap unblocked)
I <sub>C(ON)</sub>	On-State Collector Current	600	-	-	μΑ	I <sub>F</sub> = 10 mA, V <sub>CE</sub> = 5 V

Notes:

(1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum of 20 grams force may be applied to leads when soldering.

(2) Derate linearly 1.33 mW/° C above 25° C.

(3) Derate linearly 2.0 mW/° C above 25° C.

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